

ISL6522B

Buck and Synchronous Rectifier Pulse-Width Modulator (PWM) Controller

FN9150  
Rev 2.00  
Aug 10, 2015

The ISL6522B provides complete control and protection for a DC-DC converter optimized for high-performance microprocessor applications. It is designed to drive two N-Channel MOSFETs in a synchronous rectified buck topology. The ISL6522B integrates all of the control, output adjustment, monitoring and protection functions into a single package.

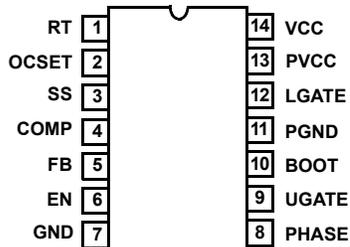
The output voltage of the converter can be precisely regulated to as low as 0.8V, with a maximum tolerance of ±1% over temperature and line voltage variations.

The ISL6522B provides simple, single feedback loop, voltage-mode control with fast transient response. It includes a 200kHz free-running triangle-wave oscillator that is adjustable from below 50kHz to over 1MHz. The error amplifier features a 15MHz gain-bandwidth product and 6V/μs slew rate which enables high converter bandwidth for fast transient performance. The resulting PWM duty ratio ranges from 0-100%.

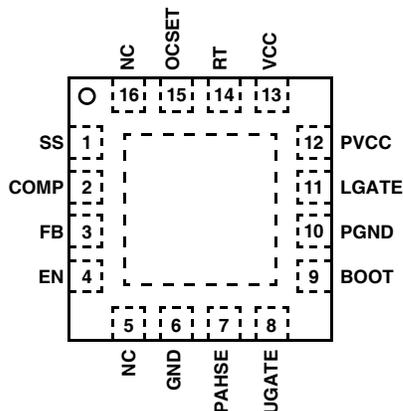
The ISL6522B protects against overcurrent conditions by inhibiting PWM operation. The ISL6522B monitors the current by using the  $r_{DS(ON)}$  of the upper MOSFET which eliminates the need for a current sensing resistor.

Pinouts

ISL6522B (SOIC)  
TOP VIEW



ISL6522B (QFN)  
TOP VIEW



Features

- Drives two N-Channel MOSFETs
- Operates from +5V or +12V input
- Simple single-loop control design
  - Voltage-mode PWM control
- Fast transient response
  - High-bandwidth error amplifier
  - Full 0–100% duty ratio
- Excellent output voltage regulation
  - 0.8V internal reference
  - ±1% over line voltage and temperature
- Overcurrent fault monitor
  - Does not require extra current sensing element
  - Uses MOSFETs  $r_{DS(ON)}$
- Converter can source and sink current
- Pre-Biased Load Start Up
- Small converter size
  - Constant frequency operation
  - 200kHz free-running oscillator programmable from 50kHz to over 1MHz
- 14-lead SOIC package and 16-lead 5x5mm QFN Package
- QFN Package
  - Compliant to JEDEC PUB95 MO-220 QFN-Quad Flat No Leads-Product Outline
  - Near Chip-Scale Package Footprint; Improves PCB Efficiency and Thinner in Profile
- Pb-Free Available (RoHS Compliant)

Applications

- Power supply for Pentium®, Pentium Pro, PowerPC® and AlphaPC™ microprocessors
- FPGA Core DC/DC Converters
- Low-voltage distributed power supplies

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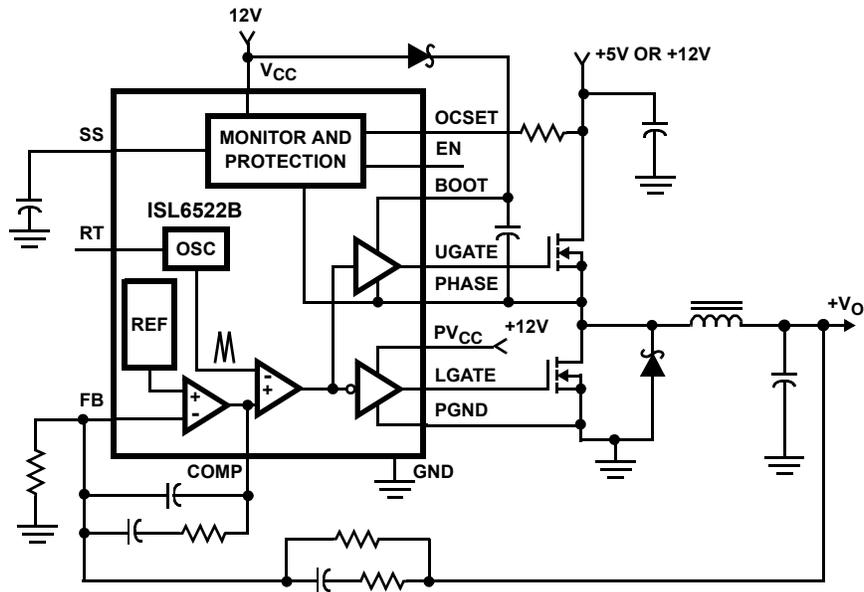
**Ordering Information**

<b>PART NUMBER</b>	<b>TEMP. RANGE (°C)</b>	<b>PACKAGE</b>	<b>PKG. DWG. #</b>
ISL6522BIBZ* (See Note)	-40 to 85	14 Ld SOIC (Pb-free)	M14.15
ISL6522BIRZ* (See Note)	-40 to 85	16 Ld 5x5 QFN (Pb-free)	L16.5x5B

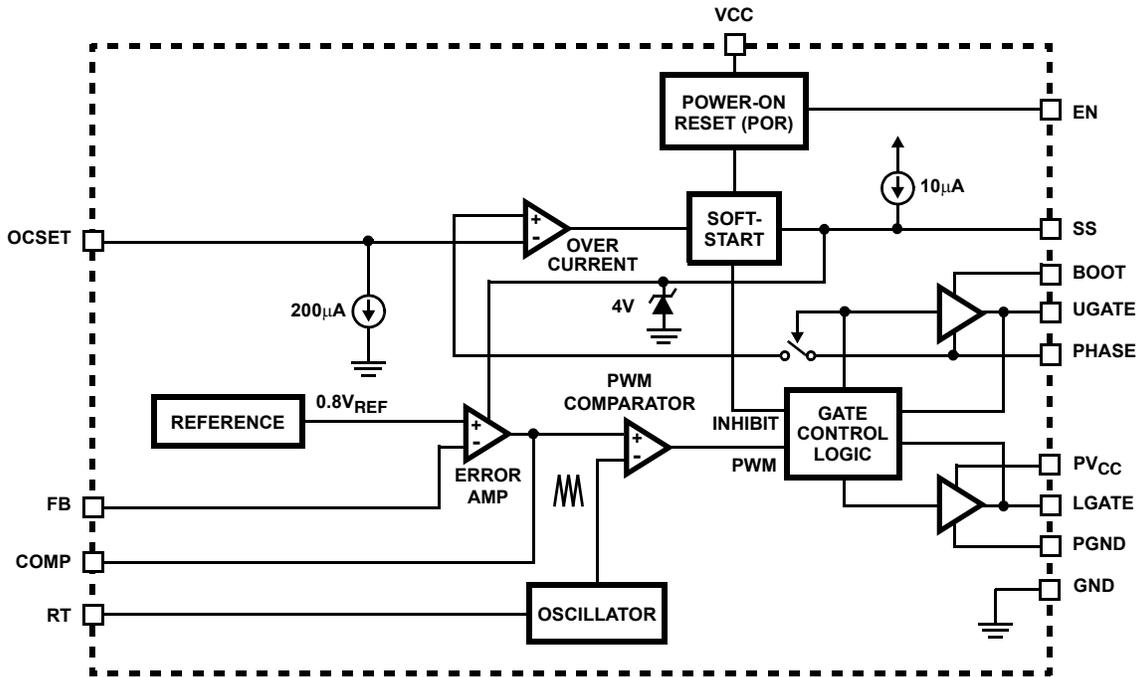
\*Add "-T\*" suffix for tape and reel.

NOTE: Intersil Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

**Typical Application**



**Block Diagram**



**Absolute Maximum Ratings**

Supply Voltage, $V_{CC}$ .....	+15.0V
Boot Voltage, $V_{BOOT} - V_{PHASE}$ .....	+15.0V
Input, Output or I/O Voltage .....	GND -0.3V to $V_{CC} +0.3V$
ESD Classification .....	Class 2

**Recommended Operating Conditions**

Supply Voltage, $V_{CC}$ .....	+12V $\pm$ 10%
Ambient Temperature Range, ISL6522BC .....	0°C to 70°C
Ambient Temperature Range, ISL6522BI .....	-40°C to 85°C
Junction Temperature Range, ISL6522BC .....	0°C to 125°C
Junction Temperature Range, ISL6522BI .....	-40°C to 125°C

**Thermal Information**

Thermal Resistance (Typical, Note 1) ...	$\theta_{JA}$ (°C/W)	$\theta_{JC}$ (°C/W)
SOIC Package (Note 1) .....	67	n/a
QFN Package (Notes 2, 3) .....	36	5
Maximum Junction Temperature .....	150°C	
Maximum Storage Temperature Range .....	-65°C to 150°C	
Maximum Lead Temperature (Soldering 10s) .....	300°C (SOIC - Lead Tips Only)	

**CAUTION:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

**NOTES:**

- $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- $\theta_{JA}$  is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
- For  $\theta_{JC}$ , the "case temp" location is the center of the exposed metal pad on the package underside.

**Electrical Specifications** Recommended Operating Conditions, Unless Otherwise Noted

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b><math>V_{CC}</math> SUPPLY CURRENT</b>						
Nominal Supply	$I_{CC}$	EN = $V_{CC}$ ; UGATE and LGATE Open	-	5	-	mA
Shutdown Supply		EN = 0V	-	50	100	$\mu$ A
<b>POWER-ON RESET</b>						
Rising $V_{CC}$ Threshold		$V_{OCSET} = 4.5VDC$	-	-	10.4	V
Falling $V_{CC}$ Threshold		$V_{OCSET} = 4.5VDC$	8.1	-	-	V
Enable-Input Threshold Voltage		ISL6522BC, $V_{OCSET} = 4.5VDC$	0.8	-	2.0	V
		ISL6522BI, $V_{OCSET} = 4.5VDC$	0.8	-	2.1	V
Rising $V_{OCSET}$ Threshold			-	1.27	-	V
<b>OSCILLATOR</b>						
Free Running Frequency		ISL6522BC, $R_T = OPEN$ , $V_{CC} = 12$	175	200	230	kHz
		ISL6522BI, $R_T = OPEN$ , $V_{CC} = 12$	160	200	230	
Total Variation		$6k\Omega < R_T \text{ to GND} < 200k\Omega$	-20	-	+20	%
Ramp Amplitude	$\Delta V_{OSC}$	$R_T = OPEN$	-	1.9	-	$V_{P-P}$
<b>REFERENCE</b>						
Reference Voltage Tolerance	$V_{REF}$	Commercial	-1	-	+1	%
		Industrial	-2	-	+1	%
Reference Voltage			-	0.800	-	V
<b>ERROR AMPLIFIER</b>						
DC Gain			-	88	-	dB
Gain-Bandwidth Product	GBW		-	15	-	MHz
Slew Rate	SR	COMP = 10pF	-	6	-	V/ $\mu$ s

**Electrical Specifications** Recommended Operating Conditions, Unless Otherwise Noted (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Soft START</b>						
Soft-Start Current	$I_{SS}$		-	10	-	$\mu A$
Peak Soft Start Voltage	$V_{SS}$		-	4.5	-	V
<b>GATE DRIVERS</b>						
Upper Gate Source	$I_{UGATE}$	$V_{BOOT} - V_{PHASE} = 12V, V_{UGATE} = 6V$	350	500	-	mA
Upper Gate Sink	$R_{UGATE}$	ISL6522BC, $I_{UGATE} = 0.3A$	-	5.0	8.75	$\Omega$
		ISL6522BI, $I_{UGATE} = 0.3A$	-	5.0	9.25	$\Omega$
Lower Gate Source	$I_{LGATE}$	$V_{CC} = 12V, V_{LGATE} = 6V$	300	450	-	mA
Lower Gate Sink	$R_{LGATE}$	ISL6522BC, $I_{LGATE} = 0.3A$	-	3.2	5.55	$\Omega$
		ISL6522BI, $I_{LGATE} = 0.3A$	-	3.2	5.85	$\Omega$
<b>PROTECTION</b>						
OCSET Current Source	$I_{OCSET}$	$V_{OCSET} = 4.5VDC$	170	200	230	$\mu A$

**Typical Performance Curves**

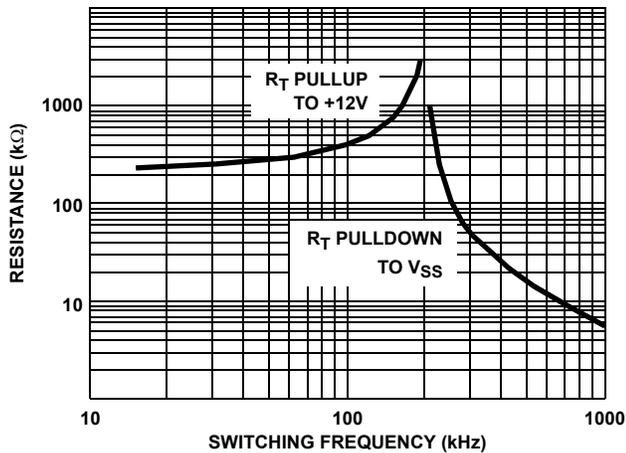


FIGURE 1.  $R_T$  RESISTANCE vs FREQUENCY

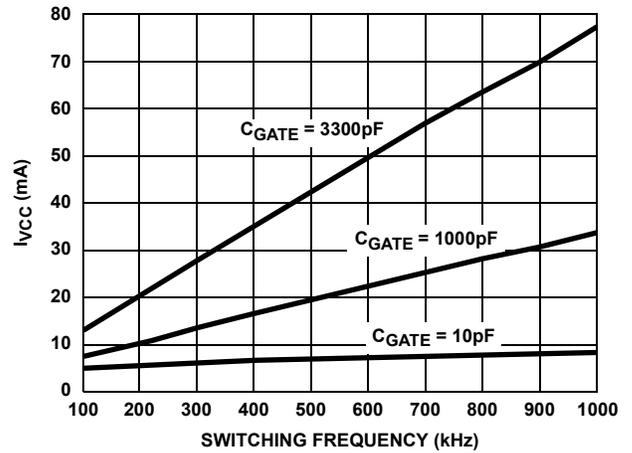
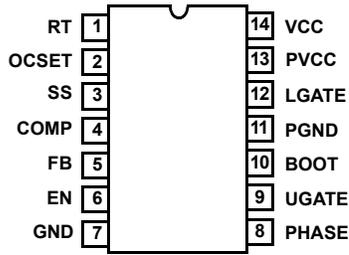


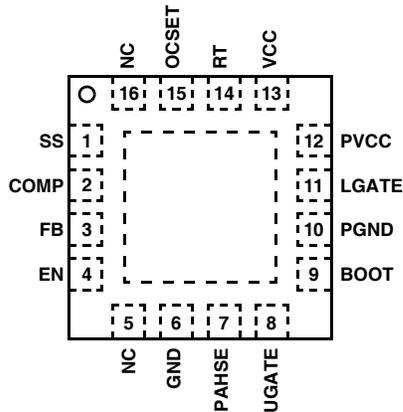
FIGURE 2. BIAS SUPPLY CURRENT vs FREQUENCY

## Functional Pin Descriptions

ISL6522B (SOIC)  
TOP VIEW



ISL6522B (QFN)  
TOP VIEW



### RT

This pin provides oscillator switching frequency adjustment. By placing a resistor ( $R_T$ ) from this pin to GND, the nominal 200kHz switching frequency is increased according to the following equation:

$$f_s \approx 200\text{kHz} + \frac{5 \cdot 10^6}{R_T} \quad (R_T \text{ to GND})$$

Conversely, connecting a pull-up resistor ( $R_T$ ) from this pin to  $V_{CC}$  reduces the switching frequency according to the following equation:

$$f_s \approx 200\text{kHz} - \frac{4 \cdot 10^7}{R_T} \quad (R_T \text{ to } 12\text{V})$$

### OCSET

Connect a resistor ( $R_{OCSET}$ ) from this pin to the drain of the upper MOSFET.  $R_{OCSET}$ , an internal 200 $\mu$ A current source ( $I_{OCS}$ ), and the upper MOSFET on-resistance ( $r_{DS(ON)}$ ) set the converter overcurrent (OC) trip point according to the following equation:

$$I_{PEAK} = \frac{I_{OCS} \cdot R_{OCSET}}{r_{DS(ON)}}$$

An overcurrent trip cycles the soft-start function.

### SS

Connect a capacitor from this pin to ground. This capacitor, along with an internal 10 $\mu$ A current source, sets the soft-start interval of the converter.

### COMP and FB

COMP and FB are the available external pins of the error amplifier. The FB pin is the inverting input of the error amplifier and the COMP pin is the error amplifier output. These pins are used to compensate the voltage-control feedback loop of the converter.

### EN

This pin is the open-collector enable pin. Pull this pin below 1V to disable the converter. In shutdown, the soft-start pin is discharged and the UGATE and LGATE pins are held low.

### GND

Signal ground for the IC. All voltage levels are measured with respect to this pin.

### PHASE

Connect the PHASE pin to the upper MOSFET source. This pin is used to monitor the voltage drop across the MOSFET for overcurrent protection. This pin also provides the return path for the upper gate drive.

### UGATE

Connect UGATE to the upper MOSFET gate. This pin provides the gate drive for the upper MOSFET. This pin is also monitored by the adaptive shoot through protection circuitry to determine when the upper MOSFET has turned off.

### BOOT

This pin provides bias voltage to the upper MOSFET driver. A bootstrap circuit may be used to create a BOOT voltage suitable to drive a standard N-Channel MOSFET.

### PGND

This is the power ground connection. Tie the lower MOSFET source to this pin.

### LGATE

Connect LGATE to the lower MOSFET gate. This pin provides the gate drive for the lower MOSFET. This pin is also monitored by the adaptive shoot through protection circuitry to determine when the lower MOSFET has turned off.

### PVCC

Provide a bias supply for the lower gate drive to this pin.

### VCC

Provide a 12V bias supply for the chip to this pin.

## Functional Description

### Initialization

The ISL6522B automatically initializes upon receipt of power. Special sequencing of the input supplies is not necessary. The Power-On Reset (POR) function continually monitors the input supply voltages and the enable (EN) pin. The POR monitors the bias voltage at the VCC pin and the input voltage ( $V_{IN}$ ) on the OCSET pin. The level on OCSET is equal to  $V_{IN}$  Less a fixed voltage drop (see overcurrent protection). With the EN pin held to  $V_{CC}$ , the POR function initiates soft-start operation after both input supply voltages exceed their POR thresholds. For operation with a single +12V power source,  $V_{IN}$  and  $V_{CC}$  are equivalent and the +12V power source must exceed the rising  $V_{CC}$  threshold before POR initiates operation.

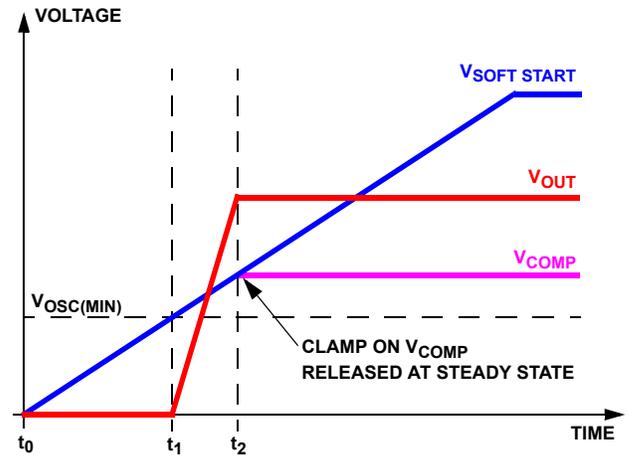
The POR function inhibits operation with the chip disabled (EN pin low). With both input supplies above their POR thresholds, transitioning the EN pin high initiates a soft-start interval.

### Soft-Start

The POR function initiates the soft-start sequence. An internal  $10\mu\text{A}$  current source charges an external capacitor ( $C_{SS}$ ) on the SS pin to 4V. Soft-start clamps the error amplifier output (COMP pin) to the SS pin voltage. Figure 3 shows the soft-start interval. At  $t_1$  in Figure 3, the SS and COMP voltages reach the valley of the oscillator's triangle wave. The oscillator's triangular waveform is compared to the ramping error amplifier voltage. This generates PHASE pulses of increasing width that charge the output capacitor(s). This interval of increasing pulse width continues to  $t_2$ , at which point the output is in regulation and the clamp on the COMP pin is released. This method provides a rapid and controlled output voltage rise.

During Soft-Start, the ISL6522B controls the regulator in a standard buck fashion. The lower MOSFET is not enabled during soft-start. The body diode of the MOSFET or the external diode, if used, will conduct when the upper MOSFET is OFF. Once the output has reached regulation, the lower MOSFET is enabled and the regulator is controlled as a synchronous buck regulator. This allows the ISL6522B regulator to start into a pre-biased output.

During Soft Start, the ISL6522B functions as a standard buck converter by disabling the lower MOSFET. This is done by holding the LGATE pin LOW. If there is not a diode in parallel with the lower MOSFET, the body diode of the lower MOSFET will conduct when the upper MOSFET is off. Once the SS pin has reached its peak value, the lower MOSFET is enabled and the ISL6522B functions as a synchronous buck converter.



$$t_1 = \frac{C_{SS}}{I_{SS}} \cdot V_{OSC(MIN)}$$

$$t_{SoftStart} = t_2 - t_1 = \frac{C_{SS}}{I_{SS}} \cdot \frac{V_{OUT_{SteadyState}}}{V_{IN}} \cdot \Delta V_{OSC}$$

Where:  $C_{SS}$  = Soft Start Capacitor  
 $I_{SS}$  = Soft Start Current =  $10\mu\text{A}$   
 $V_{OSC(MIN)}$  = Bottom of Oscillator = 1.35V  
 $V_{IN}$  = Input Voltage  
 $\Delta V_{OSC}$  = Peak to Peak Oscillator Voltage = 1.9V  
 $V_{OUT_{SteadyState}}$  = Steady State Output Voltage

FIGURE 3. SOFT-START INTERVAL

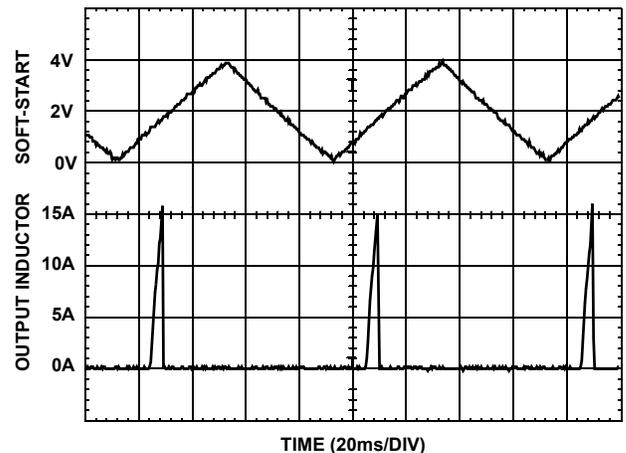


FIGURE 4. OVERCURRENT OPERATION

## Overcurrent Protection

The overcurrent function protects the converter from a shorted output by using the upper MOSFETs on-resistance,  $r_{DS(ON)}$  to monitor the current. This method enhances the converter's efficiency and reduces cost by eliminating a current sensing resistor.

The overcurrent function cycles the soft-start function in a hiccup mode to provide fault protection. A resistor ( $R_{OCSET}$ ) programs the overcurrent trip level. An internal 200 $\mu$ A (typical) current sink develops a voltage across  $R_{OCSET}$  that is in reference to  $V_{IN}$ . When the voltage across the upper MOSFET (also referenced to  $V_{IN}$ ) exceeds the voltage across  $R_{OCSET}$ , the overcurrent function initiates a soft-start sequence. The soft-start function discharges  $C_{SS}$  with a 10 $\mu$ A current sink and inhibits PWM operation. The soft-start function recharges  $C_{SS}$ , and PWM operation resumes with the error amplifier clamped to the SS voltage. Should an overload occur while recharging  $C_{SS}$ , the soft-start function inhibits PWM operation while fully charging  $C_{SS}$  to 4V to complete its cycle. Figure 4 shows this operation with an overload condition. Note that the inductor current increases to over 15A during the  $C_{SS}$  charging interval and causes an overcurrent trip. The converter dissipates very little power with this method. The measured input power for the conditions of Figure 4 is 2.5W.

The overcurrent function will trip at a peak inductor current ( $I_{PEAK}$ ) determined by:

$$I_{PEAK} = \frac{I_{OCSET} \cdot R_{OCSET}}{r_{DS(ON)}}$$

where  $I_{OCSET}$  is the internal OCSET current source (200 $\mu$ A is typical). The OC trip point varies mainly due to the MOSFETs  $r_{DS(ON)}$  variations. To avoid overcurrent tripping in the normal operating load range, find the  $R_{OCSET}$  resistor from the equation above with:

The maximum  $r_{DS(ON)}$  at the highest junction temperature.

1. The minimum  $I_{OCSET}$  from the specification table.
2. Determine  $I_{PEAK}$  for  $I_{PEAK} > I_{OUT(MAX)} + (\Delta I)/2$ , where  $\Delta I$  is the output inductor ripple current.

For an equation for the ripple current see the section under component guidelines titled *Output Inductor Selection*.

A small ceramic capacitor should be placed in parallel with  $R_{OCSET}$  to smooth the voltage across  $R_{OCSET}$  in the presence of switching noise on the input voltage.

## Current Sinking

The ISL6522B incorporates a MOSFET shoot-through protection method which allows a converter to sink current as well as source current. Care should be exercised when designing a converter with the ISL6522B when it is known that the converter may sink current.

When the converter is sinking current, it is behaving as a boost converter that is regulating its input voltage. This means that the converter is boosting current into the  $V_{IN}$  rail, the voltage that is being down-converted. If there is nowhere for this current to go, such as to other distributed loads on the  $V_{IN}$  rail, through a voltage limiting protection device, or other methods, the capacitance on the  $V_{IN}$  bus will absorb the current. This situation will cause the voltage level of the  $V_{IN}$  rail to increase. If the voltage level of the rail is boosted to a level that exceeds the maximum voltage rating of the MOSFETs or the input capacitors, damage may occur to these parts. If the bias voltage for the ISL6522B comes from the  $V_{IN}$  rail, then the maximum voltage rating of the ISL6522B may be exceeded and the IC will experience a catastrophic failure and the converter will no longer be operational. Ensuring that there is a path for the current to follow other than the capacitance on the rail will prevent these failure modes.

## Application Guidelines

### Layout Considerations

As in any high frequency switching converter, layout is very important. Switching current from one power device to another can generate voltage transients across the impedances of the interconnecting bond wires and circuit traces. These interconnecting impedances should be minimized by using wide, short printed circuit traces. The critical components should be located as close together as possible using ground plane construction or single point grounding.

Figure 5 shows the critical power components of the converter. To minimize the voltage overshoot the interconnecting wires indicated by heavy lines should be part of ground or power plane in a printed circuit board. The components shown in Figure 6 should be located as close together as possible. Please note that the capacitors  $C_{IN}$  and  $C_O$  each represent numerous physical capacitors. Locate the ISL6522B within three inches of the MOSFETs, Q1 and Q2. The circuit traces for the MOSFETs' gate and source connections from the ISL6522B must be sized to handle up to 1A peak current.

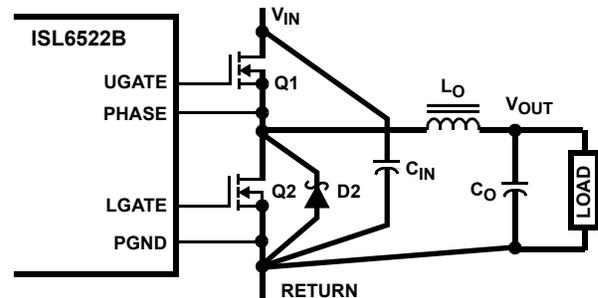


FIGURE 5. PRINTED CIRCUIT BOARD POWER AND GROUND PLANES OR ISLANDS

Figure 6 shows the circuit traces that require additional layout consideration. Use single point and ground plane construction for the circuits shown. Minimize any leakage current paths on the SS PIN and locate the capacitor,  $C_{SS}$  close to the SS pin

because the internal current source is only 10µA. Provide local V<sub>CC</sub> decoupling between VCC and GND pins. Locate the capacitor, C<sub>BOOT</sub> as close as practical to the BOOT and PHASE pins.

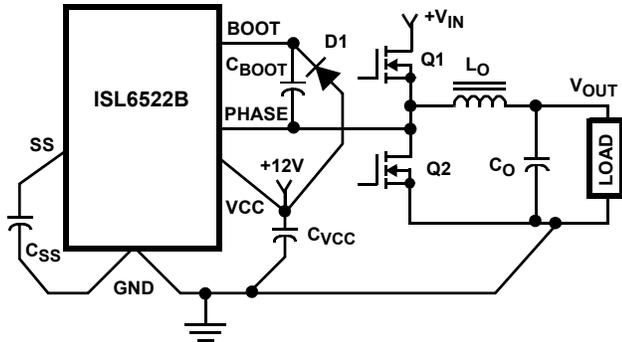


FIGURE 6. PRINTED CIRCUIT BOARD SMALL SIGNAL LAYOUT GUIDELINES

**Feedback Compensation**

Figure 7 highlights the voltage-mode control loop for a synchronous rectified buck converter. The output voltage (V<sub>OUT</sub>) is regulated to the reference voltage level. The error amplifier (error amp) output (V<sub>E/A</sub>) is compared with the oscillator (OSC) triangular wave to provide a pulse-width modulated (PWM) wave with an amplitude of V<sub>IN</sub> at the PHASE node. The PWM wave is smoothed by the output filter (L<sub>O</sub> and C<sub>O</sub>).

The modulator transfer function is the small-signal transfer function of V<sub>OUT</sub>/V<sub>E/A</sub>. This function is dominated by a DC gain and the output filter (L<sub>O</sub> and C<sub>O</sub>), with a double pole break frequency at F<sub>LC</sub> and a zero at F<sub>ESR</sub>. The DC gain of the modulator is simply the input voltage (V<sub>IN</sub>) divided by the peak-to-peak oscillator voltage ΔV<sub>OSC</sub>.

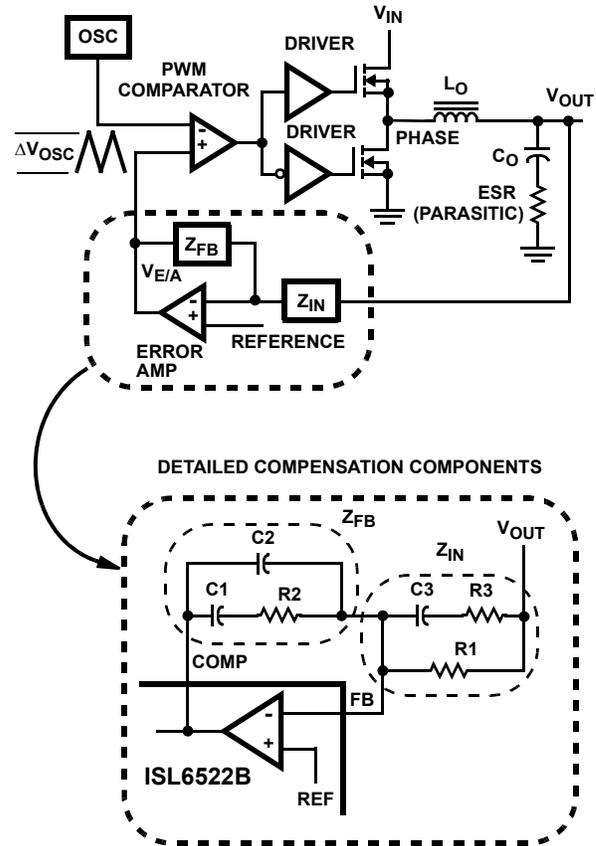


FIGURE 7. VOLTAGE - MODE BUCK CONVERTER COMPENSATION DESIGN

**Modulator Break Frequency Equations**

$$F_{LC} = \frac{1}{2\pi \cdot \sqrt{L_O \cdot C_O}} \quad F_{ESR} = \frac{1}{2\pi \cdot (ESR \cdot C_O)}$$

The compensation network consists of the error amplifier (internal to the ISL6522B) and the impedance networks Z<sub>IN</sub> and Z<sub>FB</sub>. The goal of the compensation network is to provide a closed loop transfer function with the highest 0dB crossing frequency (f<sub>0dB</sub>) and adequate phase margin. Phase margin is the difference between the closed loop phase at f<sub>0dB</sub> and 180 degrees. The equations below relate the compensation network's poles, zeros and gain to the components (R1, R2, R3, C1, C2, and C3) in Figure 8. Use these guidelines for locating the poles and zeros of the compensation network:

**Compensation Break Frequency Equations**

$$F_{Z1} = \frac{1}{2\pi \cdot R2 \cdot C1} \quad F_{P1} = \frac{1}{2\pi \cdot R2 \cdot \left(\frac{C1 \cdot C2}{C1 + C2}\right)}$$

$$F_{Z2} = \frac{1}{2\pi \cdot (R1 + R3) \cdot C3} \quad F_{P2} = \frac{1}{2\pi \cdot R3 \cdot C3}$$

1. Pick Gain (R2/R1) for desired converter bandwidth
2. Place 1<sup>ST</sup> Zero Below Filter's Double Pole (~75% F<sub>LC</sub>)

3. Place 2<sup>ND</sup> Zero at Filter's Double Pole
4. Place 1<sup>ST</sup> Pole at the ESR Zero
5. Place 2<sup>ND</sup> Pole at Half the Switching Frequency
6. Check Gain against Error Amplifier's Open-Loop Gain
7. Estimate Phase Margin - Repeat if Necessary

Figure 8 shows an asymptotic plot of the DC-DC converter's gain vs. frequency. The actual modulator gain has a high gain peak due to the high Q factor of the output filter and is not shown in Figure 8. Using the above guidelines should give a compensation gain similar to the curve plotted. The open loop error amplifier gain bounds the compensation gain. Check the compensation gain at  $F_{P2}$  with the capabilities of the error amplifier. The closed loop gain is constructed on the log-log graph of Figure 8 by adding the modulator gain (in dB) to the compensation gain (in dB). This is equivalent to multiplying the modulator transfer function to the compensation transfer function and plotting the gain.

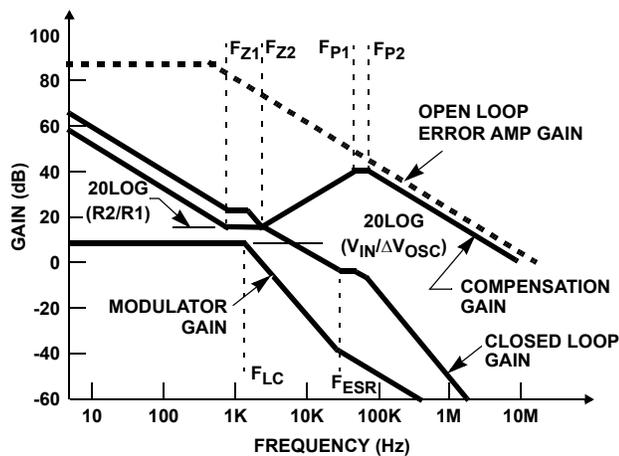


FIGURE 8. ASYMPTOTIC BODE PLOT OF CONVERTER GAIN

The compensation gain uses external impedance networks  $Z_{FB}$  and  $Z_{IN}$  to provide a stable, high bandwidth (BW) overall loop. A stable control loop has a gain crossing with -20dB/decade slope and a phase margin greater than 45 degrees. Include worst case component variations when determining phase margin.

## Component Selection Guidelines

### Output Capacitor Selection

An output capacitor is required to filter the output and supply the load transient current. The filtering requirements are a function of the switching frequency and the ripple current. The load transient requirements are a function of the slew rate ( $di/dt$ ) and the magnitude of the transient load current. These requirements are generally met with a mix of capacitors and careful layout.

Modern microprocessors produce transient load rates above 1A/ns. High frequency capacitors initially supply the transient

and slow the current load rate seen by the bulk capacitors. The bulk filter capacitor values are generally determined by the ESR (effective series resistance) and voltage rating requirements rather than actual capacitance requirements.

High frequency decoupling capacitors should be placed as close to the power pins of the load as physically possible. Be careful not to add inductance in the circuit board wiring that could cancel the usefulness of these low inductance components. Consult with the manufacturer of the load on specific decoupling requirements. For example, Intel recommends that the high frequency decoupling for the Pentium-Pro be composed of at least forty (40) 1.0 $\mu$ F ceramic capacitors in the 1206 surface-mount package.

Use only specialized low-ESR capacitors intended for switching-regulator applications for the bulk capacitors. The bulk capacitor's ESR will determine the output ripple voltage and the initial voltage drop after a high slew-rate transient. An aluminum electrolytic capacitor's ESR value is related to the case size with lower ESR available in larger case sizes. However, the equivalent series inductance (ESL) of these capacitors increases with case size and can reduce the usefulness of the capacitor to high slew-rate transient loading. Unfortunately, ESL is not a specified parameter. Work with your capacitor supplier and measure the capacitor's impedance with frequency to select a suitable component. In most cases, multiple electrolytic capacitors of small case size perform better than a single large case capacitor.

### Output Inductor Selection

The output inductor is selected to meet the output voltage ripple requirements and minimize the converter's response time to the load transient. The inductor value determines the converter's ripple current and the ripple voltage is a function of the ripple current. The ripple voltage and current are approximated by the following equations:

$$\Delta I = \frac{V_{IN} - V_{OUT}}{F_s \times L} \cdot \frac{V_{OUT}}{V_{IN}} \quad \Delta V_{OUT} = \Delta I \times ESR$$

Increasing the value of inductance reduces the ripple current and voltage. However, the large inductance values reduce the converter's response time to a load transient.

One of the parameters limiting the converter's response to a load transient is the time required to change the inductor current. Given a sufficiently fast control loop design, the ISL6522B will provide either 0% or 100% duty cycle in response to a load transient. The response time is the time required to slew the inductor current from an initial current value to the transient current level. During this interval the difference between the inductor current and the transient current level must be supplied by the output capacitor. Minimizing the response time can minimize the output capacitance required.

The response time to a transient is different for the application of load and the removal of load. The following equations give the approximate response time interval for application and removal of a transient load:

$$t_{\text{RISE}} = \frac{L_O \times I_{\text{TRAN}}}{V_{\text{IN}} - V_{\text{OUT}}} \quad t_{\text{FALL}} = \frac{L_O \times I_{\text{TRAN}}}{V_{\text{OUT}}}$$

where:  $I_{\text{TRAN}}$  is the transient load current step,  $t_{\text{RISE}}$  is the response time to the application of load, and  $t_{\text{FALL}}$  is the response time to the removal of load. With a +5V input source, the worst case response time can be either at the application or removal of load and dependent upon the output voltage setting. Be sure to check both of these equations at the minimum and maximum output levels for the worst case response time.

### Input Capacitor Selection

Use a mix of input bypass capacitors to control the voltage overshoot across the MOSFETs. Use small ceramic capacitors for high frequency decoupling and bulk capacitors to supply the current needed each time Q1 turns on. Place the small ceramic capacitors physically close to the MOSFETs and between the drain of Q1 and the source of Q2.

The important parameters for the bulk input capacitor are the voltage rating and the RMS current rating. For reliable operation, select the bulk capacitor with voltage and current ratings above the maximum input voltage and largest RMS current required by the circuit. The capacitor voltage rating should be at least 1.25 times greater than the maximum input voltage and a voltage rating of 1.5 times is a conservative guideline. The RMS current rating requirement for the input capacitor of a buck regulator is approximately 1/2 the DC load current.

For a through-hole design, several electrolytic capacitors (Panasonic HFQ series or Nichicon PL series or Sanyo MV-GX or equivalent) may be needed. For surface mount designs, solid tantalum capacitors can be used, but caution must be exercised with regard to the capacitor surge current rating. These capacitors must be capable of handling the surge-current at power-up. The TPS series available from AVX, and the 593D series from Sprague are both surge current tested.

### MOSFET Selection/Considerations

The ISL6522B requires two N-Channel power MOSFETs. These should be selected based upon  $r_{\text{DS(ON)}}$ , gate supply requirements, and thermal management requirements.

In high-current applications, the MOSFET power dissipation, package selection and heatsink are the dominant design factors. The power dissipation includes two loss components; conduction loss and switching loss. The conduction losses are the largest component of power dissipation for both the upper and the lower MOSFETs. These losses are distributed between the two MOSFETs according to duty factor. The switching losses seen when sourcing current will be different from

the switching losses seen when sinking current. When sourcing current, the upper MOSFET realizes most of the switching losses. The lower switch realizes most of the switching losses when the converter is sinking current (see the equations below).

#### Losses while Sourcing Current

$$P_{\text{UPPER}} = I_o^2 \times r_{\text{DS(ON)}} \times D + \frac{1}{2} \cdot I_o \times V_{\text{IN}} \times t_{\text{SW}} \times F_S$$

$$P_{\text{LOWER}} = I_o^2 \times r_{\text{DS(ON)}} \times (1 - D)$$

#### Losses while Sinking Current

$$P_{\text{UPPER}} = I_o^2 \times r_{\text{DS(ON)}} \times D$$

$$P_{\text{LOWER}} = I_o^2 \times r_{\text{DS(ON)}} \times (1 - D) + \frac{1}{2} \cdot I_o \times V_{\text{IN}} \times t_{\text{SW}} \times F_S$$

Where: D is the duty cycle =  $V_{\text{OUT}} / V_{\text{IN}}$ ,  
 $t_{\text{SW}}$  is the switching interval, and  
 $F_S$  is the switching frequency.

These equations assume linear voltage-current transitions and do not adequately model power loss due the reverse-recovery of the upper and lower MOSFET's body diode. The gate-charge losses are dissipated by the ISL6522B and do not heat the MOSFETs. However, large gate-charge increases the switching interval,  $t_{\text{SW}}$  which increases the upper MOSFET switching losses. Ensure that both MOSFETs are within their maximum junction temperature at high ambient temperature by calculating the temperature rise according to package thermal-resistance specifications. A separate heatsink may be necessary depending upon MOSFET power, package type, ambient temperature and air flow.

Standard-gate MOSFETs are normally recommended for use with the ISL6522B. However, logic-level gate MOSFETs can be used under special circumstances. The input voltage, upper gate drive level, and the MOSFETs absolute gate-to-source voltage rating determine whether logic-level MOSFETs are appropriate.

Figure 9 shows the upper gate drive (BOOT pin) supplied by a bootstrap circuit from  $V_{\text{CC}}$ . The boot capacitor,  $C_{\text{BOOT}}$  develops a floating supply voltage referenced to the PHASE pin. This supply is refreshed each cycle to a voltage of  $V_{\text{CC}}$  less the boot diode drop ( $V_D$ ) when the lower MOSFET, Q2 turns on. A logic-level MOSFET can only be used for Q1 if the MOSFETs absolute gate-to-source voltage rating exceeds the maximum voltage applied to  $V_{\text{CC}}$ . For Q2, a logic-level MOSFET can be used if its absolute gate-to-source voltage rating exceeds the maximum voltage applied to  $V_{\text{CC}}$ .

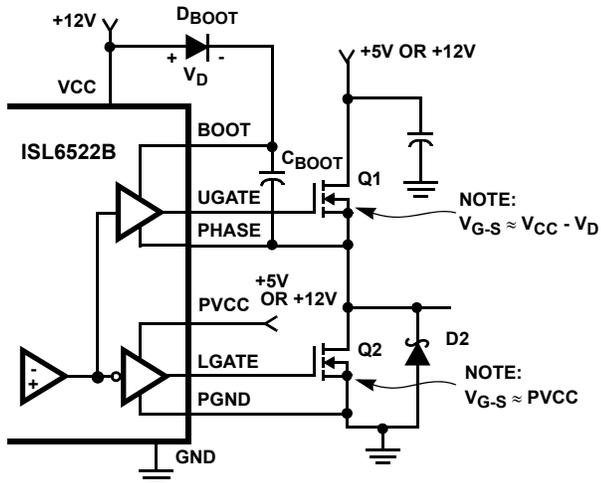
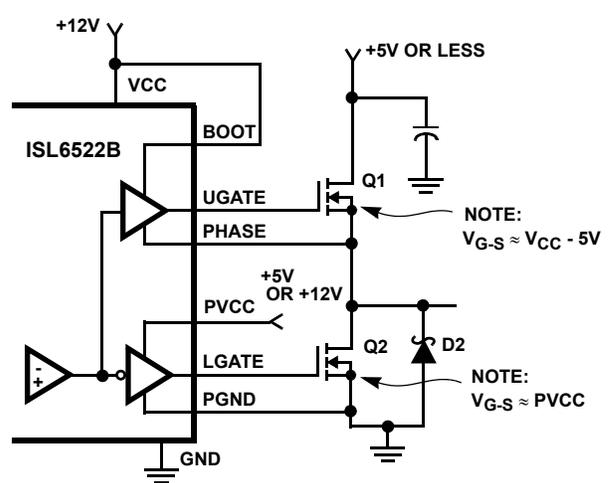


FIGURE 9. UPPER GATE DRIVE - BOOTSTRAP OPTION

Figure 10 shows the upper gate drive supplied by a direct connection to  $V_{CC}$ . This option should only be used in converter systems where the main input voltage is  $+5V_{DC}$  or less. The peak upper gate-to-source voltage is approximately  $V_{CC}$  less the input supply. For  $+5V$  main power and  $+12V_{DC}$  for the bias, the gate-to-source voltage of Q1 is 7V. A logic-level MOSFET is a good choice for Q1 and a logic-level MOSFET can be used for Q2 if its absolute gate-to-source voltage rating exceeds the maximum voltage applied to  $PV_{CC}$ .

FIGURE 10. UPPER GATE DRIVE - DIRECT  $V_{CC}$  DRIVE OPTION

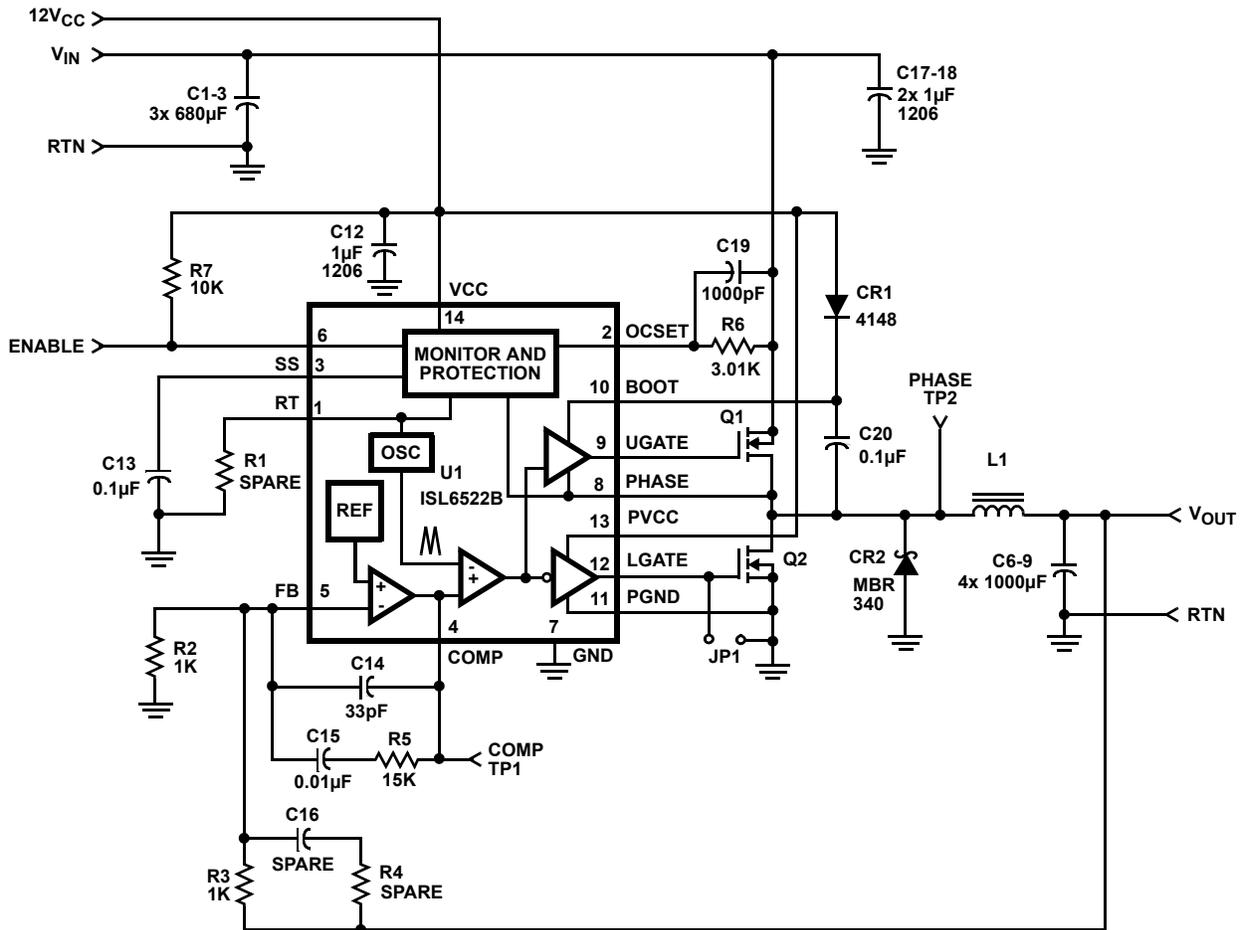
### Schottky Selection

Rectifier D2 is a clamp that catches the negative inductor swing during the dead time between turning off the lower MOSFET and turning on the upper MOSFET. The diode must be a Schottky type to prevent the lossy parasitic MOSFET body diode from conducting. It is acceptable to omit the diode and let the body diode of the lower MOSFET clamp the negative inductor swing, but efficiency will drop one or two percent as a result. The diode's rated reverse breakdown voltage must be greater than the maximum input voltage.

## ISL6522B DC-DC Converter Application Circuit

Figure 11 shows a DC-DC converter circuit for a microprocessor application, originally designed to employ the HIP6006 controller. Given the similarities between the HIP6006 and ISL6522B controllers, the circuit can be implemented using the ISL6522B controller without any

modifications. Detailed information on the circuit, including a complete bill of materials and circuit board description, can be found in Application Note AN9722. See Intersil's home page on the web: <http://www.intersil.com>.



### Component Selection Notes:

- C1-C3 - Three each 680µF 25W VDC, Sanyo MV-GX or equivalent.
- C6-C9 - Four each 1000µF 6.3W VDC, Sanyo MV-GX or equivalent.
- L1 - Core: micrometals T50-52B; winding: ten turns of 17AWG.
- CR1 - 1N4148 or equivalent.
- CR2 - 3A, 40V Schottky, Motorola MBR340 or equivalent.
- Q1, Q2 - Fairchild MOSFET; RFP25N05

FIGURE 11. DC-DC CONVERTER APPLICATION CIRCUIT

## Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to the web to make sure that you have the latest revision.

DATE	REVISION	CHANGE
August 10, 2015	FN9150.2	Added Rev History beginning with Rev 2. Added About Intersil Verbiage. Updated Ordering Information Table on page 2. Updated M14.15 and L16.5X5B PODs to most recent revisions. Change for both is as follows: Added land pattern and moved dimensions from table onto drawing.

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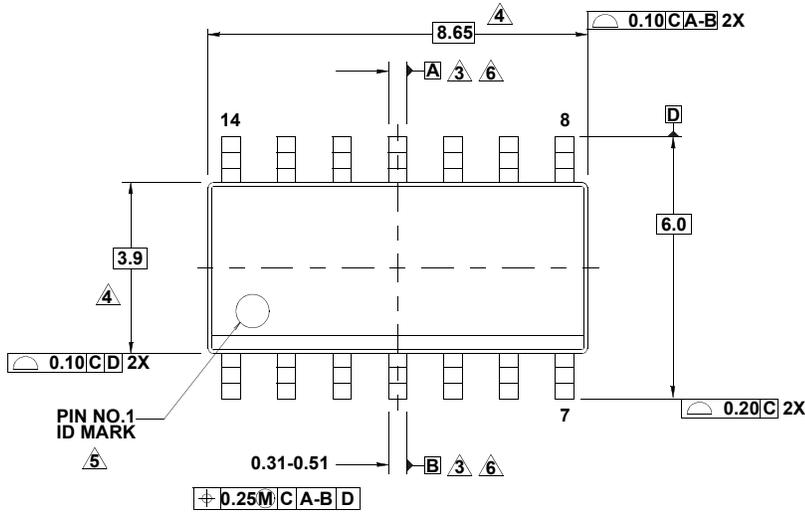
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# Package Outline Drawing

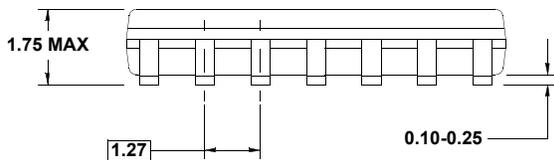
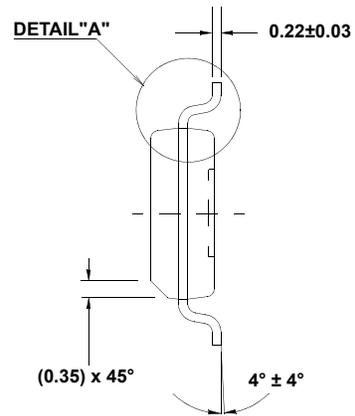
## M14.15

14 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

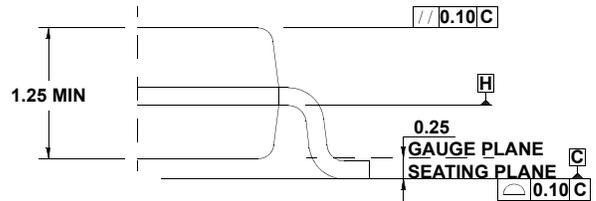
Rev 1, 10/09



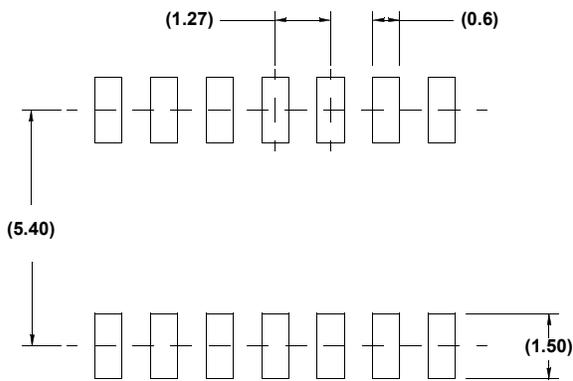
TOP VIEW



SIDE VIEW



DETAIL "A"



TYPICAL RECOMMENDED LAND PATTERN

**NOTES:**

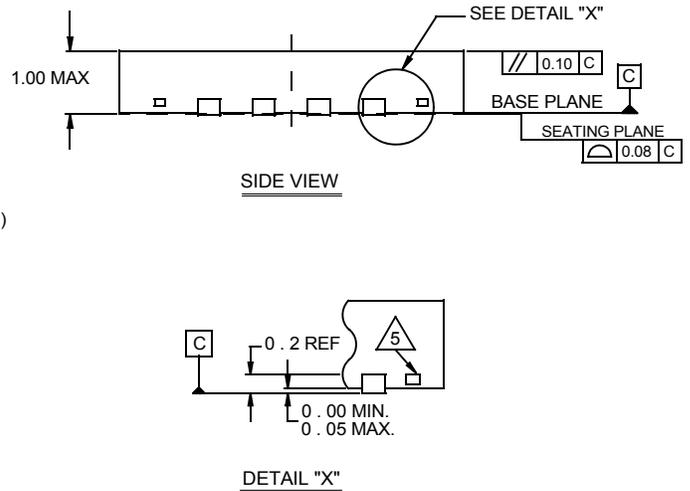
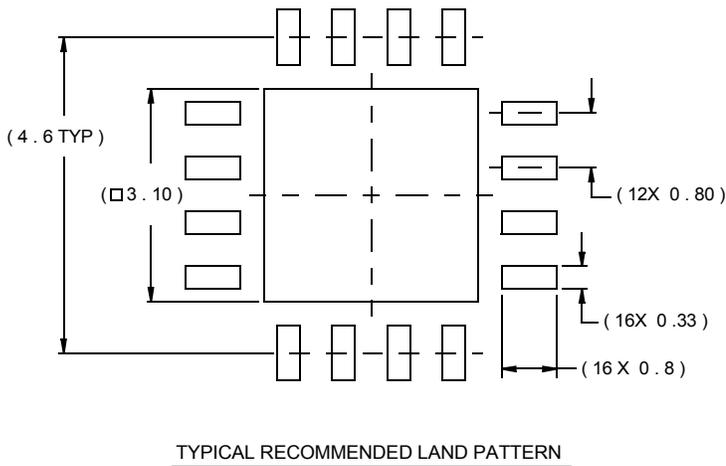
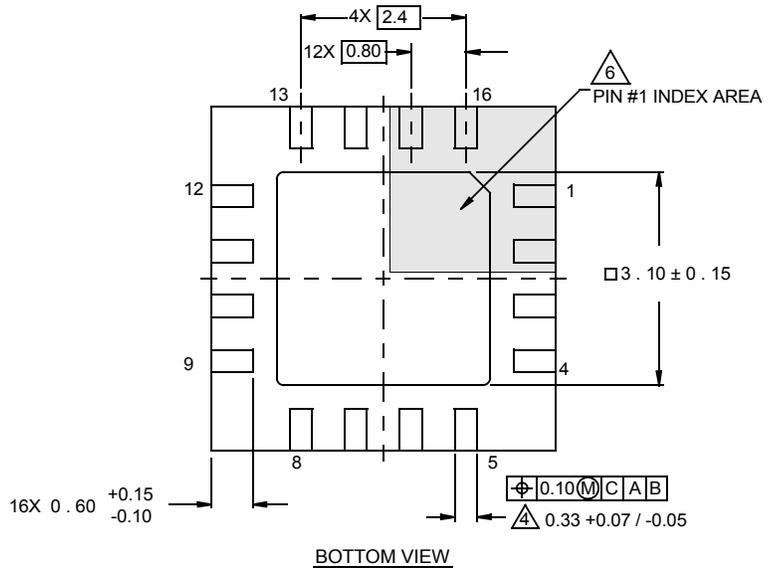
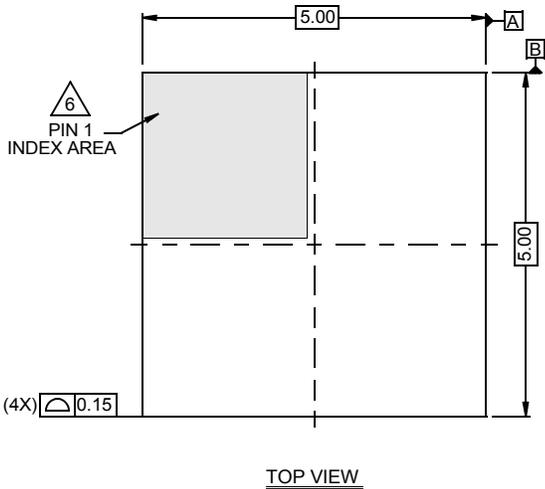
1. Dimensions are in millimeters.  
Dimensions in ( ) for Reference Only.
2. Dimensioning and tolerancing conform to AMSEY14.5m-1994.
3. Datums A and B to be determined at Datum H.
4. Dimension does not include interlead flash or protrusions.  
Interlead flash or protrusions shall not exceed 0.25mm per side.
5. The pin #1 identifier may be either a mold or mark feature.
6. Does not include dambar protrusion. Allowable dambar protrusion shall be 0.10mm total in excess of lead width at maximum condition.
7. Reference to JEDEC MS-012-AB.

# Package Outline Drawing

## L16.5x5B

16 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE

Rev 2, 02/08



NOTES:

1. Dimensions are in millimeters.  
Dimensions in ( ) for Reference Only.
2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
3. Unless otherwise specified, tolerance : Decimal  $\pm 0.05$
4. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
5. Tiebar shown (if present) is a non-functional feature.
6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.